

SPECIFICATIONS

Customer	
Product Name	Wire Wound Chip Ceramic Inductor
Sunlord Part Number	MWSD1005C□□□□TM8□
Customer Part Number	

☒ New Released, ☐ Revised]

SPEC No.: MWSD02180000

【This SPEC is total 15 pages including specifications and appendix.】

【ROHS Compliant Parts】

Approved By	Checked By	Issued By

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【For Customer approval Only】

Date: _____

Qualification Status: ☐ Full ☐ Restricted ☐ Rejected

Approved By	Verified By	Re-checked By	Checked By

Comments:

【Version change history】

Rev.	Effective Date	Changed Contents	Change reasons	Approved By
01	/	New release	/	Qintian Hou

【Precautions】

1. Magnetic materials shall be far away from parts to avoid impacts on their electrical characteristics.
2. Parts could be damaged by external mechanical pressure or stacked heavy objects, as well as strong shaking & dropping.
3. Please do not store parts in bulk to prevent coils and parts being damaged.
4. Oversized external force to parts on PCB may lead to parts being damaged or slipped off.
5. Please do not use parts on edge or top of PCB board in your design to avoid parts being damaged during PCB is moved.
6. Please use flux contained with resin since the highly acidic (Chlorine content more than 0.2 wt%) or water-soluble one could damage the insulation film of wires, then causing short circuit of parts.
7. Please do not use the brush to clean product or its surroundings. If you use the brush to clean product or its surroundings on PCB, copper wire may be broke, causing the product open .



1. Scope

This specification applies to the MWSD1005C□□□□TM8□ series of Wire Wound Chip Ceramic Inductor.

2. Product Description and Identification (Part Number)

1) Description

Wire Wound Chip Ceramic Inductor, 1005, XXX nH± X% @XXXMHz, XXXΩ, XXX mA

2) Product Identification (Part Number)

MWS **D** **1005** **C** □□□ □ **I** **M8**□
 ① ② ③ ④ ⑤ ⑥ ⑦ ⑧

① Type	
MWS	Wire Wound Chip Radio Frequency Inductor

③ External Dimensions [L X W] (mm)	
1005	1.0 X 0.5

⑤ Nominal Inductance (nH)	
Example	Nominal Value
1N0	1.0
10N	10
R10	100

⑦ Packing	
B	Bulk Package
T	Tape & Reel

② Process	
D	Dip

④ Material Code	
Example	Nominal Value
C	Ceramic

⑥ Inductance Tolerance	
B	±0.1nH
C	±0.2nH
S	±0.3nH
D	±0.5nH
G	±2%
H	±3%
J	±5%

⑧ Internal Code	
M81	Internal code

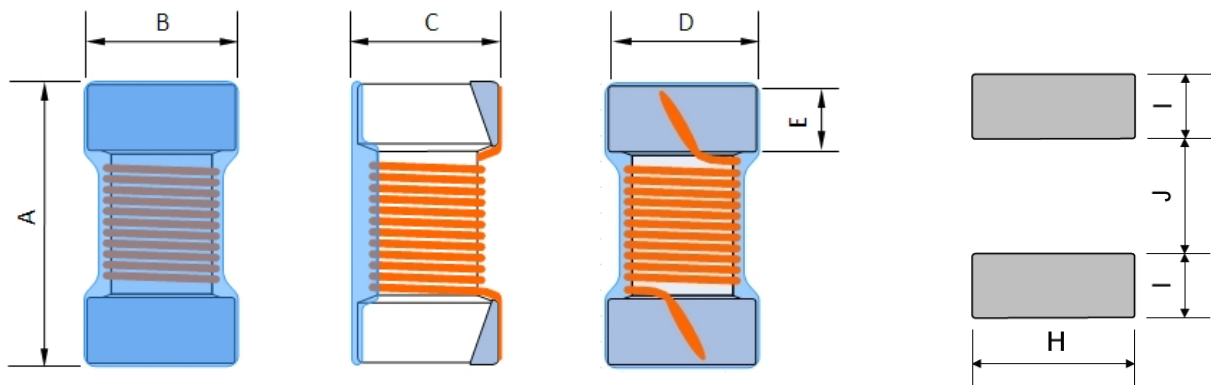
3. Electrical Characteristics

Please refer to Item 5.

- Operating and storage temperature range (individual chip without packing): -40℃ to +125℃
- Storage temperature range (packaging conditions): -10℃~+40℃ and RH 70% (Max.)

4. Shape and Dimensions

- Dimensions: See the following.

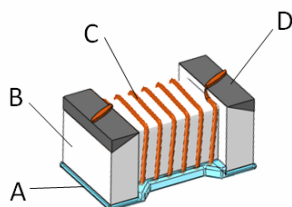


Unit: mm

A	B	C	D	E REF.	F	H REF.	I REF.	J REF.
1.1±0.1	0.6±0.1	0.6±0.1	0.5±0.1	0.20	0.2±0.1	0.65	0.35	0.50

- Electrode Coplanarity: 0.1mm Max.

3) Structure: See the following.



No.	Components	Material
A	Coating	Ultraviolet epoxy resin
B	Core	Ceramic
C	Wire	Polyurethane system enameled copper wire
D	Electrodes	Mo-Mn with Ni and Sn plating

5. Electrical Characteristics

I. MWSD1005C□□□□TM8□ Series

Part Number	Inductance	Tolerance	Min. Quality Factor	L/Q Test Freq.	Max. DC Resistance	Max. Rated Current	Min. Self-resonant Frequency
Units	nH	-	—	MHz	Ω	mA	GHz
Symbol	L	-	Q	Freq.	DCR	I _r	S.R.F
MWSD1005C1N3□TM81	1.3	C,S,D,K	20	100/250	0.012	3150	18.0
MWSD1005C1N5□TM81	1.5	B,C,S,D,K	20	100/250	0.028	2100	18.0
MWSD1005C1N6□TM81	1.6	B,C,S,D,K	20	100/250	0.045	1450	18.0
MWSD1005C1N7□TM81	1.7	B,C,S,D,K	20	100/250	0.065	1150	18.0
MWSD1005C1N8□TM81	1.8	B,C,S,D,K	20	100/250	0.065	1150	18.0
MWSD1005C2N2□TM81	2.2	B,C,S,D,K	30	100/250	0.022	2530	15.5
MWSD1005C2N3□TM81	2.3	B,C,S,D,K	30	100/250	0.022	2530	15.5
MWSD1005C2N4□TM81	2.4	B,C,S,D,K	30	100/250	0.022	2530	15.5
MWSD1005C2N5□TM81	2.5	B,C,S,D,K	30	100/250	0.030	2100	15.5
MWSD1005C2N6□TM81	2.6	B,C,S,D,K	30	100/250	0.035	1950	14.5
MWSD1005C2N7□TM81	2.7	B,C,S,D,K	28	100/250	0.047	1500	14.0
MWSD1005C2N8□TM81	2.8	B,C,S,D,K	27	100/250	0.047	1500	13.5
MWSD1005C2N9□TM81	2.9	B,C,S,D,K	25	100/250	0.047	1500	12.5
MWSD1005C3N0□TM81	3.0	B,C,S,D,K	20	100/250	0.063	1350	12.5
MWSD1005C3N3□TM81	3.3	B,C,S,D,K	30	100/250	0.030	2000	14.0
MWSD1005C3N4□TM81	3.4	B,C,S,D,J,K	30	100/250	0.030	1950	10.0
MWSD1005C3N5□TM81	3.5	B,C,S,D,J,K	30	100/250	0.030	1950	10.0
MWSD1005C3N6□TM81	3.6	B,C,S,D,J,K	30	100/250	0.030	1950	10.0
MWSD1005C3N7□TM81	3.7	B,C,S,D,J,K	35	100/250	0.030	1950	10.0
MWSD1005C3N8□TM81	3.8	B,C,S,D,J,K	35	100/250	0.030	1950	10.0
MWSD1005C3N9□TM81	3.9	B,C,S,D,J,K	35	100/250	0.030	1950	10.0
MWSD1005C4N0□TM81	4.0	B,C,S,D,J,K	30	100/250	0.030	1950	10.0
MWSD1005C4N1□TM81	4.1	B,C,S,D,J,K	30	100/250	0.044	1800	9.6
MWSD1005C4N2□TM81	4.2	B,C,S,D,J,K	30	100/250	0.044	1800	9.6
MWSD1005C4N3□TM81	4.3	B,C,S,D,J,K	32	100/250	0.044	1800	9.6
MWSD1005C4N4□TM81	4.4	B,C,S,D,J,K	34	100/250	0.052	1600	9.6
MWSD1005C4N5□TM81	4.5	B,C,S,D,J,K	34	100/250	0.060	1450	9.6
MWSD1005C4N6□TM81	4.6	B,C,S,D,J,K	32	100/250	0.060	1450	9.6
MWSD1005C4N7□TM81	4.7	B,C,S,D,J,K	31	100/250	0.071	1200	8.0
MWSD1005C4N8□TM81	4.8	B,C,S,D,J,K	30	100/250	0.071	1200	8.0
MWSD1005C4N9□TM81	4.9	B,C,S,D,J,K	27	100/250	0.071	1200	8.0
MWSD1005C5N0□TM81	5.0	B,C,S,D,J,K	32	100/250	0.040	1770	10.0
MWSD1005C5N1□TM81	5.1	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N2□TM81	5.2	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N3□TM81	5.3	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N4□TM81	5.4	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N5□TM81	5.5	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N6□TM81	5.6	B,C,S,D,J,K	35	100/250	0.040	1770	8.0
MWSD1005C5N7□TM81	5.7	B,C,S,D,J,K	30	100/250	0.040	1770	8.0
MWSD1005C5N8□TM81	5.8	B,C,S,D,J,K	30	100/250	0.040	1770	8.0
MWSD1005C5N9□TM81	5.9	B,C,S,D,J,K	30	100/250	0.040	1770	8.0
MWSD1005C6N0□TM81	6.0	B,C,S,D,J,K	32	100/250	0.056	1600	8.0
MWSD1005C6N1□TM81	6.1	B,C,S,D,J,K	32	100/250	0.056	1600	8.0
MWSD1005C6N2□TM81	6.2	B,C,S,D,J,K	33	100/250	0.056	1600	8.0

Part Number	Inductance	Tolerance	Min. Quality Factor	L/Q Test Freq.	Max. DC Resistance	Max. Rated Current	Min. Self-resonant Frequency
Units	nH	-	—	MHz	Ω	mA	GHz
Symbol	L	-	Q	Freq.	DCR	I _r	S.R.F
MWSD1005C6N3□TM81	6.3	G,H,J,K	32	100/250	0.057	1600	7.8
MWSD1005C6N4□TM81	6.4	G,H,J,K	33	100/250	0.065	1380	7.0
MWSD1005C6N5□TM81	6.5	G,H,J,K	32	100/250	0.065	1380	7.0
MWSD1005C6N6□TM81	6.6	G,H,J,K	30	100/250	0.078	1280	7.0
MWSD1005C6N7□TM81	6.7	G,H,J,K	30	100/250	0.078	1280	7.0
MWSD1005C6N8□TM81	6.8	G,H,J,K	30	100/250	0.068	1450	7.0
MWSD1005C6N9□TM81	6.9	G,H,J,K	32	100/250	0.069	1420	8.5
MWSD1005C7N0□TM81	7.0	G,H,J,K	33	100/250	0.069	1420	8.0
MWSD1005C7N1□TM81	7.1	G,H,J,K	32	100/250	0.069	1420	8.0
MWSD1005C7N2□TM81	7.2	G,H,J,K	32	100/250	0.050	1700	7.0
MWSD1005C7N3□TM81	7.3	G,H,J,K	32	100/250	0.050	1700	7.0
MWSD1005C7N4□TM81	7.4	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C7N5□TM81	7.5	G,H,J,K	35	100/250	0.050	1700	7.0
MWSD1005C7N6□TM81	7.6	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C7N7□TM81	7.7	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C7N8□TM81	7.8	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C7N9□TM81	7.9	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C8N0□TM81	8.0	G,H,J,K	30	100/250	0.050	1700	7.0
MWSD1005C8N1□TM81	8.1	G,H,J,K	32	100/250	0.069	1500	6.5
MWSD1005C8N2□TM81	8.2	G,H,J,K	32	100/250	0.069	1500	6.5
MWSD1005C8N3□TM81	8.3	G,H,J,K	32	100/250	0.069	1500	6.5
MWSD1005C8N4□TM81	8.4	G,H,J,K	32	100/250	0.069	1500	6.5
MWSD1005C8N5□TM81	8.5	G,H,J,K	32	100/250	0.069	1500	6.5
MWSD1005C8N6□TM81	8.6	G,H,J,K	31	100/250	0.070	1420	6.5
MWSD1005C8N7□TM81	8.7	G,H,J,K	31	100/250	0.070	1420	6.5
MWSD1005C8N8□TM81	8.8	G,H,J,K	31	100/250	0.070	1420	6.5
MWSD1005C8N9□TM81	8.9	G,H,J,K	31	100/250	0.070	1420	6.5
MWSD1005C9N0□TM81	9.0	G,H,J,K	30	100/250	0.070	1420	6.5
MWSD1005C9N1□TM81	9.1	G,H,J,K	32	100/250	0.080	1400	6.5
MWSD1005C9N2□TM81	9.2	G,H,J,K	32	100/250	0.081	1400	6.0
MWSD1005C9N3□TM81	9.3	G,H,J,K	34	100/250	0.081	1400	6.0
MWSD1005C9N4□TM81	9.4	G,H,J,K	33	100/250	0.081	1400	6.0
MWSD1005C9N5□TM81	9.5	G,H,J,K	32	100/250	0.081	1400	6.0
MWSD1005C9N6□TM81	9.6	G,H,J,K	33	100/250	0.081	1400	6.0
MWSD1005C9N7□TM81	9.7	G,H,J,K	33	100/250	0.081	1400	6.0
MWSD1005C9N8□TM81	9.8	G,H,J,K	34	100/250	0.081	1400	6.0
MWSD1005C9N9□TM81	9.9	G,H,J,K	32	100/250	0.081	1400	6.0
MWSD1005C10N□TM81	10	G,H,J,K	31	100/250	0.081	1400	6.0
MWSD1005C11N□TM81	11	G,H,J,K	32	100/250	0.083	1400	6.2
MWSD1005C12N□TM81	12	G,H,J,K	30	100/250	0.093	1240	5.2
MWSD1005C13N□TM81	13	G,H,J,K	30	100/250	0.093	1240	5.2
MWSD1005C14N□TM81	14	G,H,J,K	31	100/250	0.111	1150	5.2
MWSD1005C15N□TM81	15	G,H,J,K	31	100/250	0.114	1150	5.5
MWSD1005C16N□TM81	16	G,H,J,K	31	100/250	0.126	1000	5.0
MWSD1005C17N□TM81	17	G,H,J,K	31	100/250	0.126	1000	5.0
MWSD1005C18N□TM81	18	G,H,J,K	30	100/250	0.130	1050	5.2
MWSD1005C19N□TM81	19	G,H,J,K	30	100/250	0.156	920	5.0
MWSD1005C20N□TM81	20	G,H,J,K	30	100/250	0.186	800	4.5
MWSD1005C21N□TM81	21	G,H,J,K	30	100/250	0.202	780	4.5
MWSD1005C22N□TM81	22	G,H,J,K	30	100/250	0.202	780	4.5
MWSD1005C23N□TM81	23	G,H,J,K	29	100/250	0.201	760	4.5
MWSD1005C24N□TM81	24	G,H,J,K	31	100/250	0.212	770	4.0
MWSD1005C25N□TM81	25	G,H,J,K	31	100/250	0.221	750	4.1
MWSD1005C26N□TM81	26	G,H,J,K	29	100/250	0.282	720	4.1

Part Number	Inductance	Tolerance	Min. Quality Factor	L/Q Test Freq.	Max. DC Resistance	Max. Rated Current	Min. Self-resonant Frequency
Units	nH	-	—	MHz	Ω	mA	GHz
Symbol	L	-	Q	Freq.	DCR	I _r	S.R.F
MWSD1005C27N□TM81	27	G,H,J,K	30	100/250	0.288	680	4.0
MWSD1005C30N□TM81	30	G,H,J,K	30	100/250	0.309	660	3.8
MWSD1005C33N□TM81	33	G,H,J,K	30	100/250	0.336	620	3.6
MWSD1005C36N□TM81	36	G,H,J,K	30	100/250	0.431	540	3.5
MWSD1005C39N□TM81	39	G,H,J,K	28	100/250	0.456	530	3.4
MWSD1005C43N□TM81	43	G,H,J,K	30	100/250	0.516	515	3.4
MWSD1005C47N□TM81	47	G,H,J,K	25	100/250	0.648	440	3.2
MWSD1005C51N□TM81	51	G,H,J,K	25	100/250	0.696	415	2.9
MWSD1005C53N□TM81	53	G,H,J,K	25	100/200	0.696	415	2.9
MWSD1005C56N□TM81	56	G,H,J,K	25	100/200	0.996	340	2.9
MWSD1005C68N□TM81	68	G,H,J,K	25	100/200	1.128	320	2.5
MWSD1005C75N□TM81	75	G,H,J,K	25	100/200	1.224	320	2.4

6. Test and Measurement Procedures

6.1 Test Conditions

Unless otherwise specified, the standard atmospheric conditions for measurement/test as:

- Ambient Temperature: $20 \pm 15^{\circ}\text{C}$
- Relative Humidity: $65\% \pm 20\%$
- Air Pressure: 86KPa to 106KPa

If any doubt on the results, measurements/tests should be made within the following limits:

- Ambient Temperature: $20 \pm 2^{\circ}\text{C}$
- Relative Humidity: $65\% \pm 5\%$
- Air Pressure: 86KPa to 106KPa

6.2 Visual Examination

- Inspection Equipment: 30 X magnifier

6.3 Electrical Test

6.3.1 DC Resistance (DCR)

- Refer to Item 5.
- Test equipment: Agilent34420A or equivalent

6.3.2 Inductance (L)

- Refer to Item 5.
- Test equipment: Agilent 4287A+Agilent 16197A or equivalent
- Test signal: -13dBm or 10mA
- Test frequency refers to Item 5.

6.3.3 Q Factor (Q)

- Refer to Item 5.
- Test equipment: Agilent 4287A+Agilent 16197A or equivalent
- Test signal: -13dBm or 10mA
- Test frequency refers to Item 5.

6.3.4 Self-Resonant Frequency (SRF)

- Refer to Item 5.
- Test equipment: Agilent E4991A+Agilent 16197A and HP 8753E or equivalent.
- Test signal: -20dBm or 50 mV

6.3.5 Rated Current

- Refer to Item 5.
- Test equipment (see Fig.6.3.5-1): Electric Power, Electric current meter, Thermometer.
- Measurement method (see Fig. 6.3.5-1):
 - Set test current to be 0mA.
 - Measure initial temperature of chip surface.
 - Gradually increase voltage and measure chip temperature for corresponding current.
- Definition of Rated Current (I_r): I_r is direct electric current as chip surface temperature rose just 20°C against chip initial surface temperature (T_a) (see Fig. 6.3.5-2).

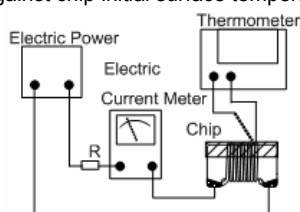


Fig.6.3.5-1

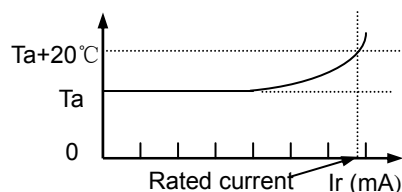
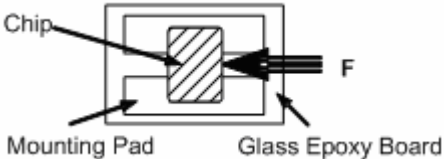
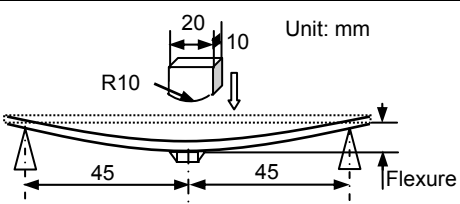
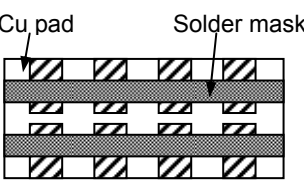
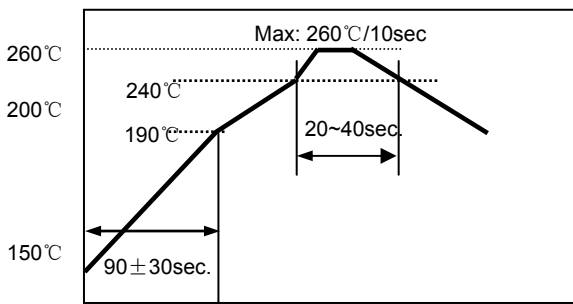
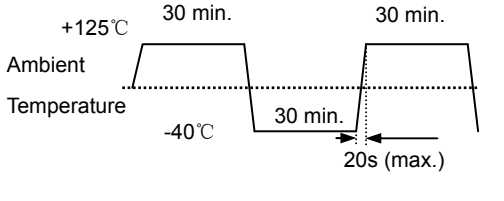


Fig. 6.3.5-2

6.4 Reliability Test

Items	Requirements	Test Methods and Remarks
6.4.1 Terminal Strength	<p>No removal or split of the termination or other defects shall occur.</p>  <p>Chip Mounting Pad Glass Epoxy Board</p>	<p>① Solder the inductor to the testing jig (glass epoxy board) using eutectic solder. Then apply a force in the direction of the arrow.</p> <p>② 4N force.</p> <p>③ Keep time: 10±1s</p> <p>④ Speed: 1.0 mm/s.</p>
6.4.2 Resistance to Flexure	<p>No visible mechanical damage.</p>  <p>Unit: mm</p> <p>R10</p> <p>45 45</p> <p>Flexure</p>	<p>① Solder the inductor to the test jig. Using a eutectic solder. Then apply a force in the direction shown as left.</p> <p>② Flexure: 2mm</p> <p>③ Pressurizing Speed: 0.5mm/sec.</p> <p>④ Keep time: 5 sec.</p>
6.4.3 Vibration	<p>① No visible mechanical damage.</p> <p>② Inductance change: within ±5%</p> <p>③ Q factor change: within ±20%</p>  <p>Cu pad Solder mask Glass Epoxy Board</p>	<p>① Solder the inductor to the testing jig (glass epoxy board) using eutectic solder.</p> <p>② The inductor shall be subjected to a simple harmonic motion having total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55 Hz.</p> <p>③ The frequency range from 10 to 55 Hz and return to 10 Hz shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours)</p>
6.4.4 Dropping	<p>① No visible mechanical damage.</p> <p>② Inductance change: within ±5%</p> <p>③ Q factor change: within ±20%</p>	Drop chip inductor 10 times on a concrete floor from a height of 100 cm.
6.4.5 Temperature coefficient	+50±100ppm/°C	<p>① Between -40°C and +125°C</p> <p>② with a reference value of +20°C</p>
6.4.6 Solderability	90% or more of electrode area shall be Coated by new solder.	<p>① Electrode of the coil shall be immersed in flux for 5 to 10 Seconds.</p> <p>② The coil shall be immersed in solder bath at a temperature of 240±5°C, Duration for 3±0.5 seconds.</p> <p>③ Solder: Sn/3.0Ag/0.5Cu</p> <p>④ Flux: 25% Resin and 75% ethanol in weight.</p>
6.4.7 Resistance to Soldering Heat	<p>① No visible mechanical damage.</p> <p>② Inductance change: within ±5%</p> <p>③ Q factor change: within ±20%</p>	<p>Re-flowing Profile:</p>  <p>260°C</p> <p>240°C</p> <p>200°C</p> <p>190°C</p> <p>150°C</p> <p>90±30sec.</p> <p>Max: 260°C/10sec</p> <p>20~40sec</p>

6.4.8 Thermal Shock	① No visible mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature, Time: -40°C for 30 ± 3 min $\rightarrow +125^{\circ}\text{C}$ for 30 ± 3 min ② Transforming interval: 20 sec. (max.) ③ Tested cycle: 100 cycles ④ The chip shall be stabilized at normal condition for 1~2 hours before measuring.
	 <p>The diagram shows a temperature profile for thermal shock testing. It starts at 'Ambient' temperature, rises to $+125^{\circ}\text{C}$ and holds for 30 min. It then falls to -40°C and holds for 30 min. This cycle is repeated. The transforming interval between the high and low temperature holds is 20s (max.).</p>	
6.4.9 Resistance to Low Temperature	① No visible mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature: $-40\pm 2^{\circ}\text{C}$ ② Duration: 1000^{+24} hours ③ The chip shall be stabilized at normal condition for 1~2 hours before measuring.
6.4.10 Resistance to High Temperature	① No mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature: $125\pm 2^{\circ}\text{C}$ ② Duration: 1000^{+24} hours ③ The chip shall be stabilized at normal condition for 1~2 hours before measuring.
6.4.11 Damp Heat (Steady States)	① No mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature: $60\pm 2^{\circ}\text{C}$, Humidity: 90% to 95% RH ② Duration: 1000^{+24} hours ③ The chip shall be stabilized at normal condition for 1~2 hours before measuring.
6.4.12 Loading Under Damp Heat	① No mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature: $60\pm 2^{\circ}\text{C}$, Humidity: 90% to 95% RH ② Duration: 1000^{+24} hours ③ Applied current: Rated current. ④ The chip shall be stabilized at normal condition for 1~2 hours before measuring.
6.4.13 Loading at High Temperature (Life Test)	① No mechanical damage. ② Inductance change: within $\pm 5\%$ ③ Q factor change: within $\pm 20\%$	① Temperature: $125\pm 2^{\circ}\text{C}$ ② Duration: 1000^{+24} hours ③ Applied current: Rated current. ④ The chip shall be stabilized at normal condition for 1~2 hours before measuring.

7. Packaging and Storage

7.1 Packaging

There are two types of packaging for the chip inductors. Please specify the packing code when ordering.

7.1.1 Bulk Packaging:

Packaging code: B, The quantity of each bag is integral multiple of 1000.

Remark: The actual quantity in a package may change sometimes.

7.1.2 Tape Carrier Packaging:

Packaging code: T

i. Tape carrier packaging are specified in attached figure **Fig.7.1-1~4**

ii. Tape carrier packaging quantity please see the following table:

Type	1005	
Tape	Paper Tape	
Quantity	Standard	10K
	Minimum	5K

(1) Taping Drawings (Unit: mm)

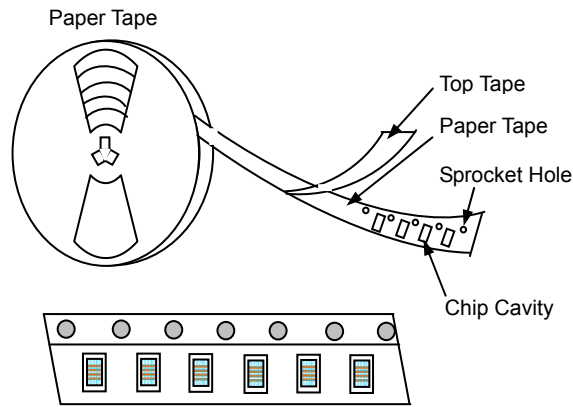


Fig. 7.1-1

Remark: The sprocket holes are to the right as the tape is pulled toward the user.

(2) Taping Dimensions (Unit: mm)

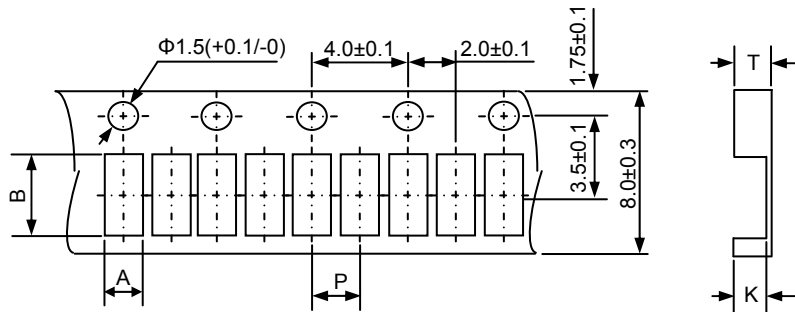


Fig. 7.1-2

Type	A	B	P	K	T
1005	0.66 ± 0.05	1.20 ± 0.05	2.0 ± 0.1	0.65 ± 0.10	0.71 ± 0.10

(3) Leader and blank portion

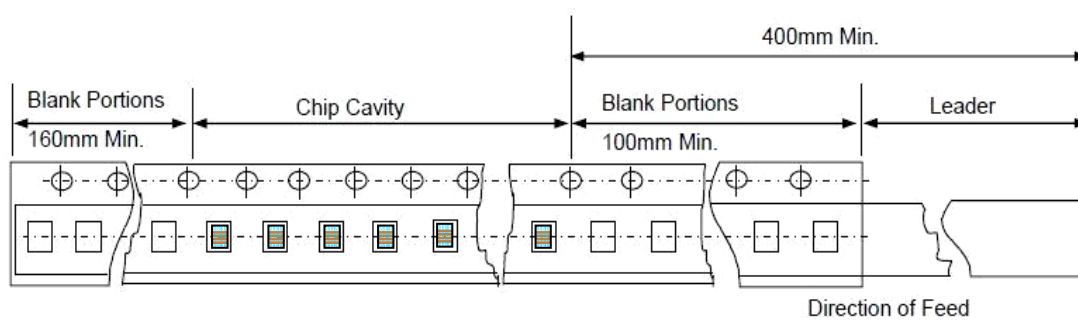


Fig. 7.1-3

(4) Reel Dimensions (Unit: mm)

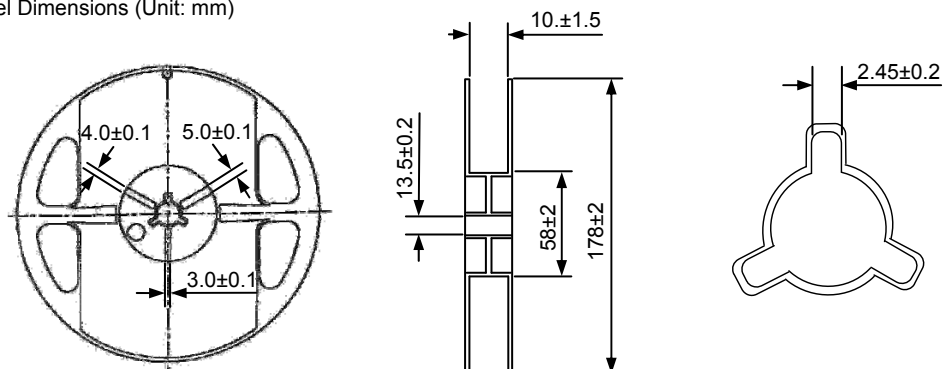
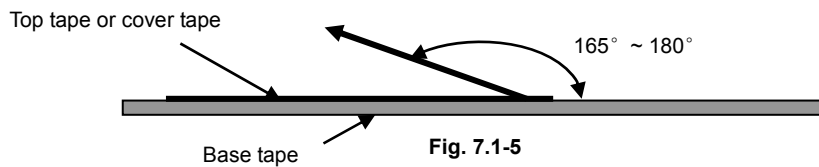


Fig. 7.1-4

(5) Peeling off force: 10gf to 70gf in the direction show below.



7.2 Storage

- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to high humidity. Package must be stored at 40°C or less and 70% RH or less.
- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to dust of harmful gas (e.g. HCl, sulfurous gas of H₂S)
- Packaging material may be deformed if package are stored where they are exposed to heat of direct sunlight.
- Minimum packages, such as polyvinyl heat-seal packages shall not be opened until they are used. If opened, use the reels as soon as possible.
- Solderability shall be guaranteed for 12 months from the date of delivery on condition that they are stored at the environment specified in specification. For those parts, which passed more than 12 months shall be checked solder-ability before use.

8. Warning and Attentions

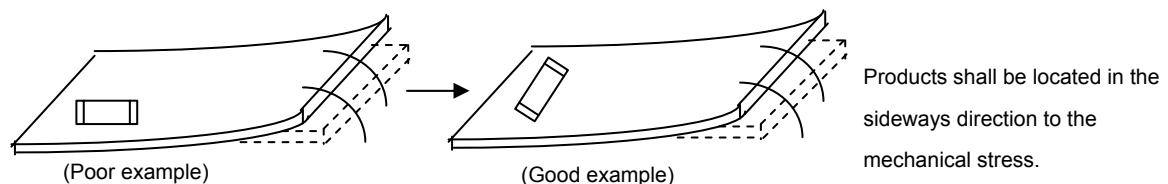
8.1 Precautions on Use

- Always wear static control bands to protect against ESD.
- Any devices used (soldering iron, measuring instruments) should be properly grounded.
- Use non-magnetic tweezers when handling the chips.
- Pre-heating when soldering, and refer to the recommended condition specified in specification.
- Don't apply current in excess of the rated current value. It may cause damage to components due to over-current.
- Keep clear of anything that may generate magnetic fields such as speakers, coils.
- When soldering, the electrical characteristics may be varied due to hot energy and mechanical stress.
- When coating products with resin, the relatively high resin curing stress may change the electrical characteristics. For exterior coating, select resin carefully so that electrical and mechanical performance of the product is not affected. Before using, please evaluate reliability with the product mounted in your application set.
- When mount chips with adhesive in preliminary assembly, do appropriate check before the soldering stage, i.e., the size of land pattern, type of adhesive, amount applied, hardening of the adhesive on proper usage and amounts of adhesive to use.
- Mounting density: Add special attention to radiating heat of products when mounting other components nearby. The excessive heat by other products may cause deterioration at joint of this product with substrate.
- Since some products are constructed like an open magnetic circuit, narrow spacing between components may cause magnetic coupling.
- Please do not give the product any excessive mechanical shocks in transportation.
- Please do not touch wires by sharp terminals such as tweezers to avoid causing any damage to wires.
- Please do not add any shock and power to the soldered product to avoid causing any damage to chip body.
- Please do not touch the electrodes by naked hand as the solderability of the external electrodes may deteriorate by grease or oil on the skin.

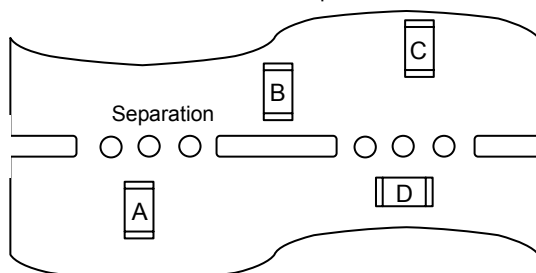
8.2 PCB Bending Design

The following shall be considered when designing and laying out PCB's.

- PCB shall be designed so that products are not subjected to the mechanical stress from board warp or deflection.



- Products location on PCB separation.



Product shall be located carefully because they may be subjected to the mechanical stress in order of A>C=B>D.

- When splitting the PCB board, or insert (remove) connector, or fasten thread after mounting components, care is required so as not to give any stress of deflection or twisting to the board. Because mechanical force may cause deterioration of the bonding strength

of electrode and solder, even crack of product body. Board separation should not be done manually, but by using appropriate devices.

8.3 Recommended PCB Design for SMT Land-Patterns

When chips are mounted on a PCB, the amount of solder used (size of fillet) and the size of PCB Land-Patterns can directly affect chip performance (such as Q). And they can also cause other soldering question (such as offset and side lap). Therefore, the following items must be carefully considered in the design of solder land patterns.

- Please use the PCB pad and solder paste we recommend, and contact us in advance if they need to be changed.
- Please use flux contained with resin since the highly acidic (Chlorine content more than 0.2 wt%) or water-soluble one could damage the insulation film of wires, then causing short circuit of parts.
- The amount of solder applied can affect the ability of chips to withstand mechanical stresses which may lead to breaking or cracking. Therefore, when designing land-patterns it is necessary to consider the appropriate size and configuration of the solder pads which in turn determines the amount of solder necessary to form the fillets.
- When more than one part is jointly soldered onto the same land or pad, the pad must be designed that each component's soldering point is separated by solder-resist.

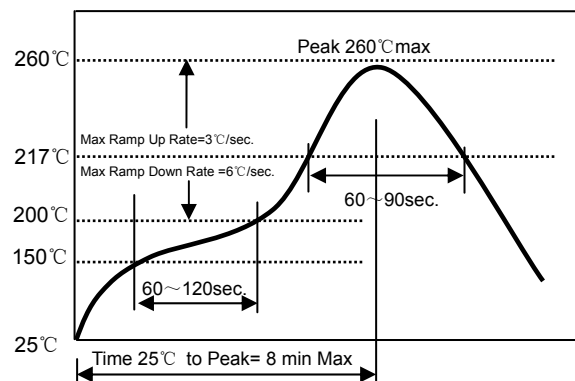
Recommended land dimensions please refer to product specification.

9. Recommended Soldering Technologies

This product is only for reflow soldering and iron soldering.

9.1 Re-flowing Profile

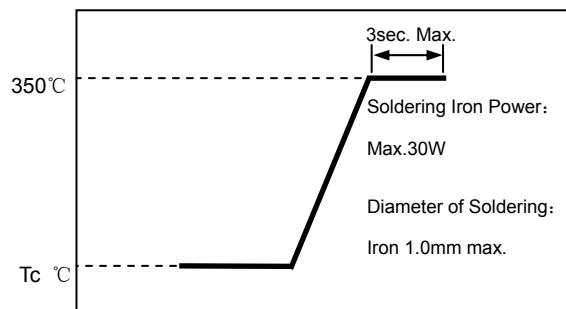
- △ Preheat condition: 150~200°C/60~120sec.
- △ Allowed time above 217°C: 60~90sec.
- △ Max temp: 260°C
- △ Max time at max temp: 10sec.
- △ Solder paste: Sn/3.0Ag/0.5Cu
- △ Allowed Reflow time: 2 times max.



[Note: The reflow profile in the above table is only for qualification and is not meant to specify board assembly profiles. Actual board assembly profiles must be based on the customer's specific board design, solder paste and process, and should not exceed the parameters as the Reflow profile shows.]

9.2 Iron Soldering Profile

- △ Iron soldering power: 30W Max.
- △ Preheat condition: 150°C/60sec.
- △ Soldering tip temperature: 350°C Max.
- △ Soldering time: 3sec. Max.
- △ Solder paste: Sn/3.0Ag/0.5Cu
- △ Iron Soldering time: 1 time max.



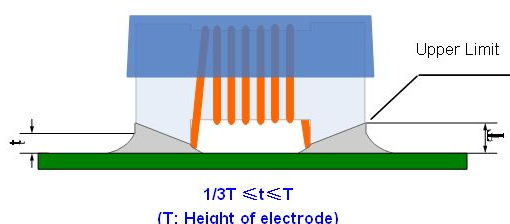
[Note: Take care not to apply the tip of the soldering iron to the terminal electrodes.]

9.3 Maintenance of heat gun (for your reference)

- △ Power output: 30W
- △ Temperature: 350°C Max
- △ Heat time: More than 5 seconds heating may cause short circuit of parts.

10. Solder Volume

Solder shall be used not to exceed as shown below.



- Accordingly increasing the solder volume, the mechanical stress to chip is also increased. Exceeding solder volume may cause the failure of mechanical or electrical performance.
- Before soldering, please ensure that the solder should not adhere to the wire part of chip.

- c. Please pay particular attention to whether there is flux remaining on surface of the wire part of chip after subjected to reflow soldering since this may causing short circuit of parts.

11. Cleaning

Products shall be cleaned on the following conditions:

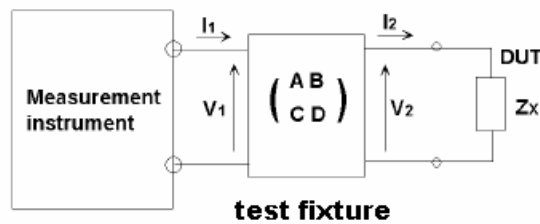
- Cleaning temperature shall be limited to 60℃ Max. (40℃ Max. for fluoride and alcohol type cleaner.)
- Ultrasonic cleaning shall comply with the following conditions, avoiding the resonance phenomenon at the mounted products and PCB.
 - Power: 20W/I Max.
 - Frequency: 28 KHz to 40 KHz
 - Time: 5 minutes Max
- Cleaner
 - Alternative cleaner
 - Isopropyl alcohol (IPA)
 - HCFC-225
 - Aqueous agent
 - Surface Active Agent Type (Clean through-750H)
 - Hydrocarbon Type (Techno Cleaner-335)
 - Higher Alcohol Type (Pine Alpha ST-100S)
 - Alkali saponifier Type (※ Aqua Cleaner 240)
 - ※ Alkali saponification shall be diluted to 20% volume with de-ionized water.
 - ※ Please contact our technical service department before using other cleaner.
- There shall be no residual flux and residual cleaner after cleaning. In the case of using aqueous agent, product shall be dried completely after rinse with de-ionized water in order to remove the cleaner.
- Some products may become slightly whitened. However, product performance or usage is not affected.
- Please take care of winding part while cleaning.
- After cleaning, parts could be subjected to the next reflow soldering till the solvent remaining on surface of parts being volatilized.

12. Supplier Information

- Supplier:
Shenzhen Sunlord Electronics Co., Ltd.
- Manufacturer:
Shenzhen Sunlord Electronics Co., Ltd.
- Manufacturing Address:
Sunlord Industrial Park, Dafuyuan Industrial Zone, Guanlan, Shenzhen, China
Zip: 518110

13. Measuring Method of Inductance

- a. Residual elements and stray elements of test fixture can be described by F-parameter as shown in the following:



$$\begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} A & B \\ C & D \end{bmatrix} \begin{bmatrix} V_2 \\ I_2 \end{bmatrix}$$

$$\begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} AV_2 + BI_2 \\ CV_2 + DI_2 \end{bmatrix}$$

Measured open impedance: $Z_{om} = \frac{A}{C}$

Measured short impedance: $Z_{sm} = \frac{B}{D} \approx -Z_{sc}$ (when uses short chip to short)

Measured short ship impedance: Z_{sc}

Measured value: $Z_x = V_1/I_1$

Impedance of DUT: $Z_x = V_2/I_2$

- b. The relation between Z_x and Z_{om} , Z_{sm} , Z_x is shown in the following:

$$Z_x = \frac{V_2}{I_2} = \frac{D}{A} * \frac{\frac{V_1}{I_1} - \frac{B}{D}}{1 - \frac{V_1}{I_1} * \frac{C}{A}} = \frac{D}{A} * \frac{Z_{xm} - \frac{B}{D}}{1 - Z_{xm} * \frac{C}{A}} = \frac{D}{A} * \frac{Z_{xm} - Z_{sm}}{1 - Z_{xm} / Z_{om}}$$

- c. L_x should be calculated with the following equation:

$$L_x = \frac{\text{Im}(Z_x)}{2\pi f} = \frac{\text{Im}(Z_{xm} + Z_{sc})}{2\pi f} = \frac{\text{Im}(Z_{xm})}{2\pi f} + \frac{\text{Im}(Z_{sc})}{2\pi f} = L_{xm} + L_{sc}$$

L_{xm}: measured chip inductor inductance

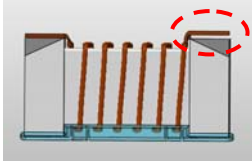
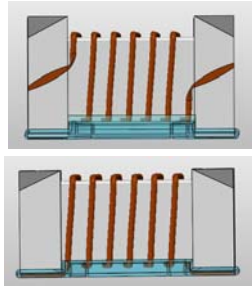
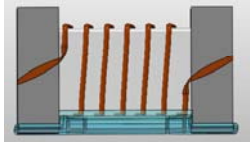
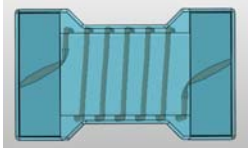
L_{sc}: measured short chip inductance

L_x: Inductance of chip inductor

- d. Compensation Value (L_{sc}) of short chip

Series	Compensation Value
MWSD1005C-M	0.68nH

Appendix : Appearance standard

File No:		Applied to Wire Wound Ceramic Inductor Series	
Effective date:			
No.	Defect Item Item	Graphic Schematic Drawing	Rejection identification Criteria
1	Wire off/ Welding Spot Off		The solder joint Welding Spot of wire break away from electrodes, or over the electrodes.
2	Solder misplace		Solder joints are not at electrode side but at the coating side or flank.
3	Coating misplace		Coating at flank
			Coating at electrodes side